NSN 5961-01-087-9432

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass and metal
Overall Length:
Between 0.430 inches and 1.860 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.551 inches and 0.559 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
10.00 amperes forward current, total rms nanoamperes
Power Rating Per Characteristic:
0.5 watts small-signal input power, common-collector peak
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0